



Small Signal Fast Switching Diodes

Features

- · Silicon Epitaxial Planar Diode
- · AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition



FREE



Applications

· Extreme fast switches

Mechanical Data

Case: DO-35

Weight: approx. 125 mg Cathode Band Color: black

Packaging Codes/Options:

TR/10 k per 13" reel (52 mm tape), 50 k/box TAP/10 k per Ammopack (52 mm tape), 50 k/box

Parts Table

Part		Ordering code	Type Marking	Remarks
1	N4154	1N4154-TR or 1N4154-TAP	1N4154	Tape and Reel/Ammopack

Absolute Maximum Ratings

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Repetitive peak reverse voltage		V_{RRM}	35	V	
Reverse voltage		V _R	25	V	
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α	
Repetitive peak forward current		I _{FRM}	500	mA	
Forward continuous current		I _F	300	mA	
Average forward current	V _R = 0	I _{FAV}	150	mA	
Power dissipation	I = 4 mm, T _L = 45 °C	P _{tot}	440	mW	
rower dissipation	$I = 4$ mm, $T_L \le 25$ °C	P _{tot}	500	mW	

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	$I = 4$ mm, $T_L = constant$	R_{thJA}	350	K/W
Junction temperature		Tj	175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C

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Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 30 mA	V _F		880	1000	mV
Reverse current	V _R = 25 V	I _R		9	100	nA
neverse current	$V_R = 25 \text{ V}, T_j = 150 ^{\circ}\text{C}$	I _R			100	μΑ
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V _(BR)	35			V
Diode capacitance	$V_R = 0$, $f = 1$ MHz, $V_{HF} = 50$ mV	C _D			4	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}$	t _{rr}			4	ns
Therefore receivery unite	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			2	ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

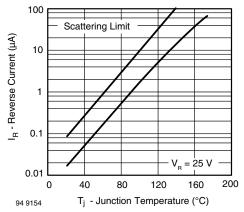


Figure 1. Reverse Current vs. Junction Temperature

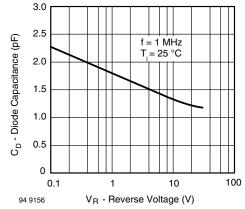


Figure 3. Diode Capacitance vs. Reverse Voltage

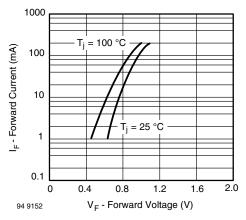
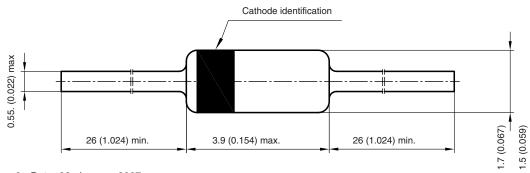


Figure 2. Forward Current vs. Forward Voltage



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Package Dimensions in millimeters (inches): DO-35



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